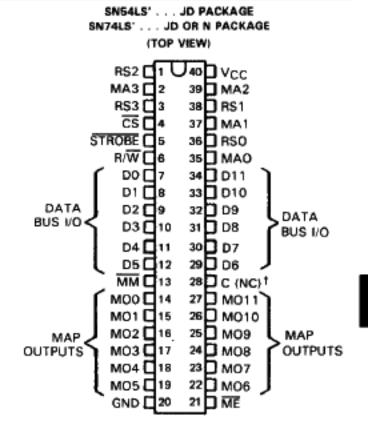
- Designed for Paged Memory Mapping
- Output Latches Provided on 'LS610 and
- Choice of 3-State or Open-Collector Map Outputs
- Compatible with TMS9900 and Other Microprocessors

| DE1/105 | OUTPUTS | MAP            |
|---------|---------|----------------|
| DEVICE  | LATCHED | OUTPUT TYPE    |
| 'LS610  | Yes     | 3-State        |
| 'LS611  | Yes     | Open-Collector |
| 'LS612  | No      | 3-State        |
| 'LS613  | No      | Open-Collector |

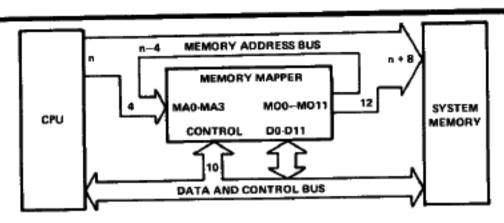
### description

Each 'LS610 through 'LS613 memory-mapper integrated circuit contains a 4-line to 16-line decoder, a 16-word by 12-bit RAM, 16 channels of 2-line to 1-line multiplexers, and other miscellaneous circuitry on a monolithic chip. Each 'LS610 and 'LS611 also contains 12 latches with an enable control.

The memory mappers are designed to expand a microprocessor's memory address capability by eight bits. Four bits of the memory address bus (see System Block Diagram) can be used to select one of 16 map registers that contain 12 bits each. These 12 bits are presented to the system memory address bus through the map output buffers along with the unused memory address bits from the CPU. However, addressable memory space without reloading the map registers is the same as would be available with the memory mapper left out. The addressable memory space is increased only by periodically reloading the map registers from the data bus. This configuration lends itself to memory utilization of 16 pages of 2(n-4) registers each without reloading (n = number of address bits available from CPU).



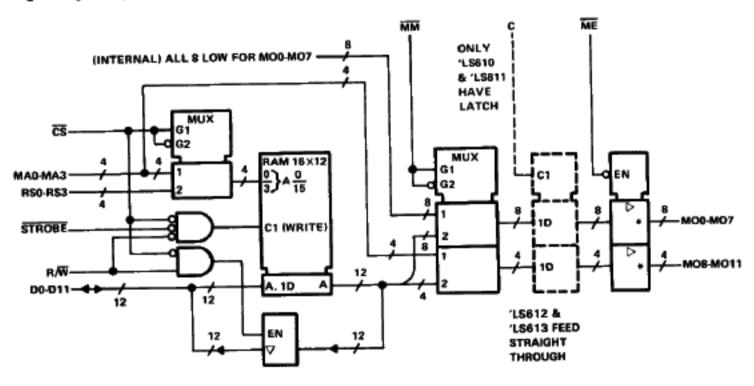
<sup>†</sup>This pin has no internal connection on 'LS612 and 'LS613



SYSTEM BLOCK DIAGRAM

These devices have four modes of operation: read, write, map, and pass. Data may be read from or loaded into the map register selected by the register select inputs (RS0 thru RS3) under control of  $R/\overline{W}$  whenever chip select ( $\overline{CS}$ ) is low. The data I/O takes place on the data bus D0 thru D7. The map operation will output the contents of the map register selected by the map address inputs (MA0 thru MA3) when  $\overline{CS}$  is high and  $\overline{MM}$  (map mode control) is low. The 'LS612 and 'LS613 output stages are transparent in this mode, while the 'LS610 and 'LS611 outputs may be transparent or latched. When  $\overline{CS}$  and  $\overline{MM}$  are both high (pass mode), the address bits on MA0 thru MA3 appear at M08-M011, respectively, (assuming appropriate latch control) with low levels in the other bit positions on the map outputs.

### logic diagram (positive logic)



"L\$610 and 'L\$612 have 3-state (\$\nabla\$) map outputs.
'L\$611 and 'L\$613 have open-collector (\$\nabla\$) map outputs.

# SN54LS610, SN54LS612, SN74LS610 THRU SN74LS613 MEMORY MAPPERS

| P             | in                    | DECODISTION   |
|---------------|-----------------------|---|
| NO.           | NAME                  | DESCRIPTION   |
| 7-12          | DO thru D11           | I/O connections to data and control bus used for reading from and writing to the map register         |
| 29-34         |                       | selected by RSO-RS3 when $\overline{\text{CS}}$ is low. Mode controlled by R/ $\overline{\text{W}}$ . |
| 36, 38, 1, 3  | RSO thru RS3          | Register select inputs for I/O operations.  |
| 6             | R/W                   | Read or write control used in I/O operations to select the condition of the data bus. When            |
|               |                       | high, the data bus outputs are active for reading the map register. When low, the data bus is         |
|               |                       | used to write into the register.  |
| 5             | STROBE                | Strobe input used to enter data into the selected map register during I/O operations.                 |
| 4             | <u>CS</u>             | Chip select input. A low input level selects the memory mapper (assuming more than one                |
|               |                       | used) for an I/O operation.   |
| 35, 37, 39, 2 | MA0 thru MA3          | Map address inputs to select one of 16 map registers when in map mode (MM low and CS                  |
| }             |                       | high).  |
| 14-19,        | MO0 thru MO11         | Map outputs. Present the map register contents to the system memory address bus in the map            |
| 22-27         |                       | mode. In the pass mode, these outputs provide the map address data on MO8-MO11 and low                |
|               |                       | levels on MO0-MO7.  |
| 13            | MM                    | Map mode input. When low, 12 bits of data are transferred from the selected map register to           |
|               |                       | the map outputs. When high (pass mode), the 4 bits present on the map address inputs                  |
| İ             |                       | MAO-MA3 are passed to the map outputs MO8-MO11, respectively, while MO0-MO7 are set                   |
|               |                       | low.  |
| 21            | ME                    | Map enable for the map outputs. A low level allows the outputs to be active while a high input        |
|               |                       | level puts the outputs at high impedance.   |
| 28            | С                     | Latch enable input for the 'LS610 and 'LS611 (no internal connection for 'LS612 and 'LS613).          |
|               |                       | A high level will transparently pass data to the map outputs. A low level will latch the outputs.     |
| 40, 20        | V <sub>CC</sub> , GND | 5 V power supply and network ground (substrate) pins.   |



### schematics of inputs and outputs EQUIVALENT OF OTHER INPUTS INPUT/OUTPUT PORTS, D0-D11 Vcc 1/0 Reg PORT VCC -INPUT: 100 Ω NOM 20 kΩ NOM MM Req = 7 k $\Omega$ NOM RS, STROBE: Req = 9 k $\Omega$ NOM CS, R/W, MA: Req = 6 k $\Omega$ NOM TYPICAL OF SN74LS611, SN74LS613 MAP OUTPUTS TYPICAL OF 'LS610, 'LS612 MAP OUTPUTS – vcc **50** Ω NOM OUTPUT OUTPUT

| absolute maximum ratings over operati   | ing free-air temperature range (unless otherwise noteu)                                   |
|---|---|
| Supply voltage, VCC (see Note 1) Input voltage: Data Bus I/O All other inputs | 7 V 5.5 V 7 V SN54LS610, SN54LS612 -55°C to 125°C SN74LS610 through SN74LS613 0°C to 70°C |
| Storage temperature range   | SN74LS610 through SN74LS613   |

NOTE 1: Voltage values are with respect to network ground terminal.

### recommended operating conditions

|                    |   |                 |              | SN54LS610<br>SN54LS612 |     |      | SI<br>SI | UNIT |       |       |
|--------------------|---|-----------------|--------------|------------------------|-----|------|----------|------|-------|-------|
|                    |   |                 |              | MIN                    | NOM | MAX  | MIN      | NOM  | MAX   |       |
| Vcc                | Supply voltage                          |                 |              | 4.5                    | 5   | 5.5  | 4.75     | 5    | 5.25  | V     |
| VIH                | High-level input voltage                |                 |              | 2                      |     |      | 2        |      |       | V     |
| VIL                | Low-level input voltage                 |                 |              |                        |     | 0.7  |          |      | 0.8   | ٧     |
| la                 | High level output gurrent               |                 | МО           |                        |     | - 12 |          |      | - 15  | mA    |
| IOH                | High-level output current               |                 | D            | <u> </u>               |     | -1   |          |      | - 2.6 |       |
| 1                  | Low-level output current                |                 | МО           | l                      |     | 12   |          |      | 24    | mA.   |
| İOL                | Low-level output current                |                 | D            | I                      |     | 4    |          |      | 8     | 11112 |
| †AVCL              | Address setup time<br>(AV before C low) | 'LS610 only     | See Figure 2 | 30                     |     |      | 30       |      |       | ns    |
| <sup>t</sup> SLSH  | Duration of strobe input pulse          |                 |              | 75                     |     |      | 75       |      |       | ns    |
| <sup>†</sup> CSLSL | CS setup time (CS low to strobe         | low)            | 1            | 20                     |     |      | 20       |      |       | ns    |
| tWLSL              | R/W setup time (R/W low to stre         | obe low)        | }            | 20                     |     |      | 20       |      |       | ns    |
| <sup>t</sup> RVSL  | RS setup time (RS valid to strob        | e low)          | 1            | 20                     |     | ,    | 20       |      |       | ns    |
| <sup>t</sup> DVSH  | Data setup time (D0-D11 valid t         | o strobe high)  | See Figure 1 | 75                     |     |      | 75       |      |       | ns    |
| tSHCSH             | CS hold time (Strobe high to CS         | high)           | 1            | 20                     |     |      | 20       |      |       | ns    |
| tSHWH              | R/W hold time (Strobe high to R         | /W high)        |              | 20                     |     |      | 20       |      |       | ns    |
| <sup>t</sup> SHRX  | RS hold time (Strobe high to RS         | invalid)        |              | 20                     |     |      | 20       |      |       | ns    |
| †SHDX              | Data hold time (Strobe high to I        | 00-D11 invalid) | ]            | 20                     |     |      | 20       |      |       | ns    |
| TA                 | Operating free-air temperature          |                 |              | - 55                   |     | 125  | 0        |      | 70    | °C    |



### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

|                | ARAMETER   | TE   | TEST CONDITIONS <sup>†</sup> |                         | SN54LS610<br>SN54LS612 |                  |       | S        | UNIT |       |              |
|----------------|------------|--|------------------------------|-------------------------|------------------------|------------------|-------|----------|------|-------|--------------|
| Ρ,             | AKAMETEN   | TEGT CONSTITUTE                                |                              |                         | MIN                    | TYP <sup>‡</sup> | MAX   | MIN      | TYP‡ | MAX   |              |
| V              |            | V <sub>CC</sub> = MIN, I <sub>1</sub> = -18 mA |                              |                         |                        |                  | -1.5  |          |      | -1.5  | V            |
| VIK            |            |  |                              | 11 2 mA                 | 2.4                    |                  |       | 2.4      |      |       |              |
| V              | МО         | V <sub>CC</sub> = MIN,                         | $V_{IH} = 2 V$               | I <sub>OH</sub> = MAX   | 2                      |                  |       | 2        |      |       | \            |
| Vон            | D          | $V_{IL} = MAX$                                 |                              | IOH = MAX               | 2.4                    |                  |       | 2.4      |      |       |              |
|                |            |  |                              | I <sub>OL</sub> = 12 mA |                        | 0.25             | 0.4   |          | 0.25 | 0.4   | ]            |
|                | мо         | Vcc = MIN.                                     | $V_{IH} = 2 V$               | I <sub>OL</sub> = 24 mA |                        |                  |       |          | 0.35 | 0.5   | l v          |
| VOL            | <u> </u>   | VIL = MAX                                      |                              | I <sub>OL</sub> = 4 mA  | 1                      | 0.25             | 0.4   |          | 0.25 | 0.4   |              |
|                | D          | 10   |                              | 1 <sub>OL</sub> = 8 mA  |                        |                  |       | L        | 0.35 | 0.5   | <b>_</b>     |
|                |            | V <sub>CC</sub> = MAX,                         |                              |                         |                        |                  | 20    |          |      | 20    | μА           |
| lozh           |            | VIL = MAX,                                     | $V_0 = 2.7 \text{ V}$        |                         | <b>├</b>               |                  | - 20  |          |      | - 20  | <del> </del> |
| 1              | МО         | VCC = MAX,                                     |                              |                         | ├                      |                  | -400  | ├──      |      | - 400 | μΑ           |
| IOZL           | D          | V <sub>IL</sub> = MAX,                         | $V_0 = 0.4 \text{ V}$        | 1                       | ┼─                     |                  | 0.1   | ┼──      |      | 0.1   |              |
| l <sub>i</sub> | D          | VCC = MAX                                      |                              | V <sub>1</sub> = 5.5 V  | ┼                      |                  | 0.1   | $\vdash$ |      | 0.1   | mA           |
| n              | All others | 1  |                              | V <sub>I</sub> = 7 V    | ┼──                    |                  | 20    | ┼        |      | 20    | μА           |
| ін             |            | V <sub>CC</sub> = MAX,                         | $V_1 = 2.7 \text{ V}$        |                         | <del>↓</del> —         |                  | -0.4  | +        |      | -0.4  | mA           |
| IJL            |            | V <sub>CC</sub> = MAX,                         | $V_1 = 0.4 \text{ V}$        |                         | -40                    |                  | - 225 | -40      |      | - 225 |              |
| los§           | MO<br>D    | VCC = MAX                                      |                              |                         | -30                    |                  | - 130 | - 30     |      | -130  | mA           |
|                |            |  | Outputs high                 | h                       | 1                      | 112              | 180   |          | 112  | 180   |              |
| 1              |            | V <sub>CC</sub> = MAX                          | Outputs low                  |                         |                        | 112              | 180   |          | 112  | 180   | mA           |
| Icc            |            | 1  | Outputs disa                 |                         | 1                      | 150              | 230   |          | 180  | 230   | <u> </u>     |

<sup>&</sup>lt;sup>†</sup>For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

### switching characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25 \,^{\circ}\text{C}$ , $C_L = 45 \,^{\circ}\text{pF}$ to GND

|                   |                      | FROM         | то       |                      |          | 'LS61 | 0   |  | LS612 | :   | UNIT |
|-------------------|----------------------|--------------|----------|----------------------|----------|-------|-----|--|-------|-----|------|
|                   | PARAMETER            | (INPUT)      | (OUTPUT) | TEST CONDITIONS      | MIN      | TYP   | MAX | MIN  | TYP   | MAX | Oldi |
| tCSLDV            | Access (enable) time | ĊS↓          | DO-11    |                      |          | 28    | 50  |  | 26    | 50  | ns   |
|                   | Access (enable) time | R/W↑         | D0-11    | $R_L = 2 k\Omega$ ,  |          | 20    | 35  |  | 20    | 35  | ns   |
| tWHDV_            | Access time          | RS           | D0-11    | See Figure 1,        |          | 49    | 75  | l  | 39    | 75  | กร   |
| <sup>t</sup> RVDV | Disable time         | R/₩↓         | D0-11    | See Notes 2 and 3    |          | 32    | 50  |  | 30    | 50  | ns   |
| tWLDZ             | Disable time         | <u>CS</u> ↑  | D0-11    | 1                    |          | 42    | 65  |  | 38    | 65  | ns   |
| tCSHDZ            | Access (enable) time | ME           | MO0-11   |                      |          | 19    | 30  |  | 17    | 30  | ns   |
| tELQV_            |                      | CS↑          | M00-11   | 1                    |          | 56    | 85  |  | 48    | 85  | ns   |
| tcshav            | Access time          | MM           | MO0-11   |                      |          | 25    | 40  |  | 22    | 40  | ns   |
| tMLQV_            | Access time          | Ct           | MO0-11   | $R_L = 667 \Omega$ , |          | 24    | 40  |  |       |     | ns   |
| tCHQV             | Access time          | MA           | MO0-11   | See Figure 2,        |          | 46    | 70  | T -  | 39    | 70  | ns   |
| tAVQV1            | Access time (MM low) | MM†          | MO0-11   | See Notes 2 and 3    | <b></b>  | 24    | 40  |  | 22    | 40  | ns   |
| VOHM              | Access time          | MIMI         | WIOO-11  |                      | <u> </u> |       |     |  |       |     |      |
| tavova            | Propagation time     | MA           | MO8-11   |                      |          | 19    | 30  |  | 13    | 30  | ns   |
| tAVQV2            | (MM high)            | <del> </del> |          | 4                    | -        | 14    | 25  | <del>                                     </del> | 14    | 25  | пѕ   |
| tEHQZ             | Disable time         | MET          | MO0-11   | 1                    | <u> </u> | 14    |     | <u> </u>   |       |     |      |

NOTES: 2. Access times are tested as tpLH and tpHL or tpZH or tpZL. Disable times are tested as tpHZ and tpLZ.

3. Load circuits and voltage waveforms are shown in Section 1.



 $<sup>^{\</sup>ddagger}$ All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25 °C.

Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

## SN74LS611, SN74LS613 MEMORY MAPPERS WITH OPEN-COLLECTOR MAP OUTPUTS

### recommended operating conditions

|                   |  |                                       |              | MIN  | NOM | MAX  | UNIT |
|-------------------|--|---------------------------------------|--------------|------|-----|------|------|
| VCC               | Supply voltage                                 | 4.75                                  | 5            | 5.25 | V   |      |      |
| VIH               | High-level input voltage                       |                                       |              | 2    |     |      | V    |
| VIL               | Low-level input voltage                        |                                       |              | 1    |     | 0.8  | V    |
| Voн               | High-level output voltage                      |                                       | МО           |      |     | 5.5  | V    |
| ЮН                | High-level output current                      |                                       | D            |      |     | -2.6 | mA   |
| lo.               | Low-level output current                       |                                       | МО           | 1    |     | 24   |      |
| lOL               | Low-level butput current                       | D                                     | 8            |      | 8   | mA   |      |
| *****             | Address setup time                             | SN74LS611 only                        | 0-5-0        | -    |     |      |      |
| †AVCL             | (AV before C low)                              | See Figure 2                          | 30           |      |     | ns   |      |
| tSLSH             | Duration of stobe input pulse                  |                                       |              | 75   |     |      | ns   |
| †CSLSL            | CS setup time (CS low to strobe low)           |                                       | 1            | 20   |     |      | ns   |
| tWLSL             | R/W setup time (R/W low to strobe low)         |                                       | 1            | 20   |     |      | ns   |
| <sup>t</sup> RVSL | RS setup time (RS valid to strobe low)         |                                       | 1            | 20   |     |      | ns   |
| <sup>t</sup> DVSH | Data setup time (D0-D11 valid to strobe high)  |                                       | See Figure 1 | 75   |     |      | ns   |
| tSHCSH            | CS hold time (Strobe high to CS high)          | CS hold time (Strobe high to CS high) |              |      |     |      | ns   |
| <sup>t</sup> SHWH | R/W hold time (Strobe high to R/W high)        | 1                                     | 20           |      |     | ns   |      |
| tSHRX             | RS hold time (Strobe high to RS invalid)       | ]                                     | 20           |      |     | ns   |      |
| †SHDX             | Data hold time (Strobe high to D0-D11 invalid) | 1                                     | 20           |      |     | ns   |      |
| TA                | Operating free-air temperature                 |                                       | 1            | 0    |     | 70   | °C   |



## electrical characteristics over recommended operating free-air temperature range (unless otherwise

| ioteu)    |             |  |                         | act                     | MIN | TYP‡ | MAX   | UNIT   |
|-----------|-------------|--|-------------------------|-------------------------|-----|------|-------|--|
| PARAMETER |             |  | TEST CONDITIO           | NS.                     |     |      | 1.5   | V  |
| Vik       |             | V <sub>CC</sub> = MIN,                           | I <sub>I</sub> = -18 mA |                         |     |      |       |  |
| Vон       | D           | V <sub>CC</sub> = MIN,<br>V <sub>IL</sub> = MAX, | $V_{IH} = 2 V$          |                         | 2.4 |      |       | >  |
|           |             | V <sub>CC</sub> = MIN,                           | VIII = 2 V              | V <sub>OH</sub> = 5.5 V |     |      | 0.1   | mA   |
| ЮН        | МО          | VCC = MIN,                                       | VIH - 2 V,              | I <sub>OL</sub> = 12 mA |     | 0.25 | 0.4   |  |
|           | мо          | V <sub>CC</sub> = MIN,                           | Viu = 2 V.              | IOL = 24 mA             |     | 0.35 | 0.5   | v  |
| VOL       | <b> </b>    | VII = MAX  | - 111                   | IOL = 4 mA              |     | 0.25 | 0.4   | i  |
| 0.2       | D           | VIL - MAX  |                         | I <sub>OL</sub> = 8 mA  |     | 0.35 | 0.5   |  |
| lozh      | D           | V <sub>CC</sub> = MAX,<br>V <sub>IL</sub> = MAX, |                         |                         |     |      | 20    | μА   |
| lozL      | D           | V <sub>CC</sub> = MAX,<br>V <sub>O</sub> = 0.4 V | V <sub>IH</sub> = 2 V,  |                         |     |      | -0.4  | mA   |
|           | <del></del> | VO = 0.4 V                                       |                         | V <sub>I</sub> = 5.5 V  |     |      | 0.1   | mA.  |
| lj.       | D           | $V_{CC} = MAX$                                   |                         | V <sub>I</sub> = 7 V    |     |      | 0.1   | <u>                                     </u> |
|           | All others  |  | V = 27V                 |                         |     |      | 20    | μА   |
| ΉΗ        |             | V <sub>CC</sub> = MAX,                           | V = 2.7 V               |                         |     |      | -0.4  | mA   |
| ЧL        |             | V <sub>CC</sub> = MAX,                           | V <sub>1</sub> = 0.4 V  |                         | -30 |      | - 130 |  |
| los§      | D           | VCC = MAX  | I o                     |                         |     | 100  | 170   | mA   |
|           |             |  | Outputs high            |                         |     | 100  | 170   |  |
| Icc       |             | V <sub>CC</sub> = MAX                            | Outputs low             |                         |     | 110  |       | ⊢ mA   |
| 1         |             |  | Outputs disable         |                         |     |      |       |  |

<sup>&</sup>lt;sup>†</sup>For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

## switching characteristics, VCC = 5 V, $TA = 25 \,^{\circ}\text{C}$ , $CL = 45 \,^{\circ}\text{F}$ to GND

|                   | FROM TO              |             |          |                      | SN74LS611 |     |     | SN74LS613  |     |    | UNIT |
|-------------------|----------------------|-------------|----------|----------------------|-----------|-----|-----|--|-----|----|------|
|                   | PARAMETER            | (INPUT)     | (OUTPUT) | TEST CONDITIONS      | MIN       | TYP | MAX | MIN  | TYP |    |      |
| tool DV           | Access (enable) time | ĊS↓         | D0-11    |                      |           | 31  | 50  | <u> </u>   | 28  | 50 | ns   |
| CSLDV             | Access (enable) time | R/W1        | D0-11    | $R_L = 2 k\Omega$ ,  |           | 23  | 35  |  | 21  | 35 | ns   |
| WHDV              | Access time          | RS          | D0-11    | See Figure 1,        |           | 51  | 75  |  | 47  | 75 | ns   |
| tRVDV             | Disable time         | R/₩↓        | D0-11    | See Notes 2 and 3    |           | 32  | 50  |  | 31  | 50 | ns   |
| tWLDZ             | Disable time         | <u>CS</u> ↑ | DO-11    | 1                    |           | 41  | 65  |  | 40  | 65 | ns   |
| CSHDZ             | Access (enable) time | ME          | MO0-11   |                      |           | 21  | 30  |  | 19  | 30 | ns   |
| tELQV_            |                      | CSt         | M00-11   | †                    |           | 57  | 90  |  | 53  | 90 | ns   |
| tCSHQV            | Access time          | MMI         | M00-11   | +                    |           | 25  | 40  |  | 25  | 40 | ns   |
| <sup>t</sup> MLQV | Access time          | C1          | MO0-11   | $R_L = 667 \Omega$ , |           | 30  | 45  |  |     |    | ns   |
| tCHQV             | Access time          |             | MO0-11   | See Figure 2,        | <b>—</b>  | 47  | 70  | 1  | 44  | 70 | ns   |
| tAVQV1            | Access time (MM low) |             | MO0-11   | See Notes 2 and 3    | -         | 31  | 50  | <del>                                     </del> | 31  | 50 | ns   |
| VDHM              | Access time          | MM1         | WOO-11   | 4                    | <b></b>   |     |     | 1  |     |    |      |
| *****             | Propagation time     | MA          | MO8-11   |                      | Į.        | 21  | 30  |  | 20  | 30 | ns   |
| tAVQV2            | (MM high)            |             | 1        | 4                    |           | 15  | 25  | $\vdash$   | 15  | 25 | ns   |
| tEHQZ             | Disable time         | MET         | MO0-11   |                      | <u> </u>  | 13  |     |  |     |    |      |

NOTES: 2. Access times are tested as tpLH and tpHL or tpZH or tpZL. Disable times are tested as tpHZ and tpLZ.



 $<sup>^{\</sup>ddagger}$ All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25 °C.

<sup>§</sup>Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

<sup>3.</sup> Load circuits and voltage waveforms are shown in Section 1.

#### explanation of letter symbols

This data sheet uses a new type of letter symbol based on JEDEC Standard 100 to describe time intervals. The format is:

#### tAB-CD

where: subscripts A and C indicate the names of the signals for which changes of state or level or establishment of state or level constitute signal events assumed to occur first and last, respectively, that is, at the beginning and end of the time interval.

Subscripts B and D indicate the direction of the transitions and/or the final states or levels of the signals represented by A and C, respectively. One or two of the following is used:

H = high or transition to high

L = low or transition to low

V = a valid steady-state level

X = unknown, changing, or "don't care" level

Z = high-impedance (off) state.

The hyphen between the B and C subscripts is omitted when no confusion is likely to occur. For these letter symbols on this data sheet, the signal names are further abbreviated as follows:

| SIGNAL NAME   | A AND C SUBSCRIPT | SIGNAL NAME | A AND C SUBSCRIPT |
|---------------|-------------------|-------------|-------------------|
| С             | С                 | MĒ          | E                 |
| <del>CS</del> | cs                | MM          | М                 |
| D0-11         | D                 | R/W         | W                 |
| MAO-MA3       | Α                 | RSO-RS3     | R                 |
| MO0-MO11      | Q                 | STROBE      | S                 |

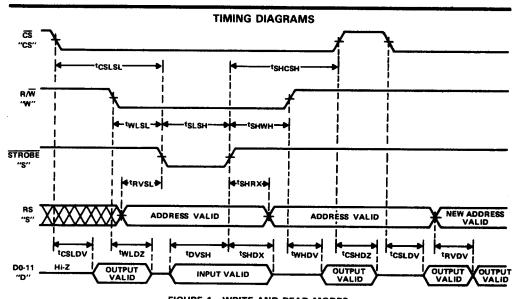


FIGURE 1. WRITE AND READ MODES



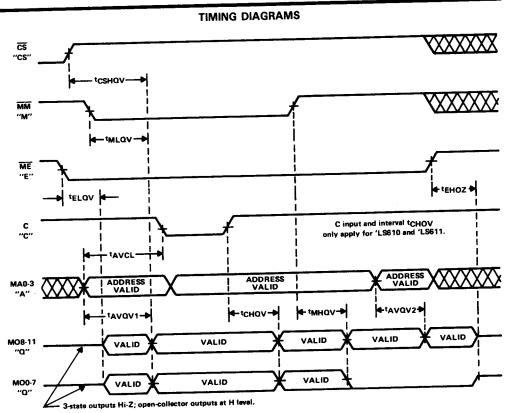


FIGURE 2. MAP AND PASS MODES

TTL Devices